## W here is the Shot Noise of a Quantum Point Contact?

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Reznikov et al. (Phys. Rev. Lett. 75, 3340 (1995)) have presented de nitive observations of nonequilibrium noise in a quantum point contact. Especially puzzling is the \anomalous" peak structure of the excess noise measured at constant current; to date it remains unexplained. We show that their experiment directly reveals the deep link between conservation principles in the electron gas and its low-dimensional, mesoscopic behavior. Key to that connection are gauge invariance and the compressibility sum rule. These are central not only to the experiment of Reznikov et al. but to the very nature of all mesoscopic transport.

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M icroscopic conservation laws are the sine qua non of transport and uctuation physics. Their dominance is even more apparent in the passage to sub-micrometer electronics. In the following, we bring to light the direct governing role of conservation in low-dimensional meso-scopic conduction, with immediate experimental consequences. Indeed, these have already been observed [1].

The prim ary global statem ents of conservation are the electron-gas sum rules [2]. Their cardinal signi cance as conserving relations is that they must be satis ed automatically by credible models of mesoscopic transport [3].

This paper details the particular and striking interplay of the compressibility sum rule and dynam ical electron relaxation. That interplay dominates the form of the carrier uctuations (noise) of a driven quasi-one-dimensional quantum point contact, so completely as to dictate the shape of its nonequilibrium noise spectrum. Our results have far-reaching implications for understanding transport in mesoscopic electron devices.

Som e years ago Reznikov, Heiblum, Shtrikman, and Mahalu [1] performed a landmark experiment on nonequilibrium noise in a quantum point contact (QPC). The electron density was freely adjusted via a gate voltage Vq, sweeping the carriers from their low-density classical regim e up to high density and degeneracy. At xed values of source-drain voltage V across the QPC, a regular sequence of peaks appeared in the noise power spectrum as the channel's carrier density was system atically increased. Analogous features were also seen by Kumar et al. [4]. The behavior at xed V is predicted by the noninteracting one-electron picture of coherent ballistic conduction, rst applied to QPC shot noise by Khlus 5]. It has since been re ned and rede ned by Landauer, Buttiker, Im ry, and many others; for an authoritative review see Ref. 6 and citations in it.

A major innovation of Reznikov et al. was to measure the nonequilibrium noise for xed levels of source-drain current I through the QPC, as well as their stan-

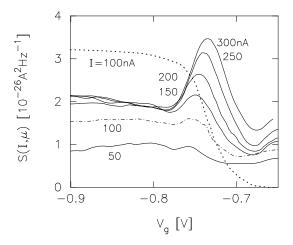


FIG. 1: Nonequilibrium current noise in a quantum point contact at  $1.5 \mathrm{K}$ , measured by Reznikov et al. [1] as a function of gate bias, at xed source-drain current. Dotted line: the most widely adopted theoretical noise model [6] typically produces a strictly monotonic noise signal at the rst subband energy threshold. That model totally fails to predict the very strong noise peaks actually observed at threshold.

dard m easurements at  $xed\ V$ . A surprise ensued. Far from the anticipated strictly monotonic fallo of spectral strength [6], the data exhibited a series of pronounced noise maxima at the lowest subband energy threshold.

Figure 1 shows the constant-current data of Ref. 1. At higher source-drain currents, a robust peak structure emerges in the noise as a function of gate bias, precisely at the location of the rst subband threshold. At I=100nA, we reproduce the conventionally predicted shotnoise curve [1,6].

Reznikov et al. remark that \the peaks near  $T_1$  = 1=2 [ie at threshold] are not expected" [1]. This is an understatement, for the observed excess-noise maxima

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contradict the accepted theoretical predictions, based on shot noise. Something quite uncommon and apparently inexplicable is going on.

In the nine years since publication of that experiment, its astonishing outcome has not been revisited. Yet the anomalous signatures are rst-hand evidence that a deep knowledge gap exists in our physical understanding of mesoscopics. This has ramications not just for quantum point contacts, but for all low-dimensional devices.

We now analyze the Reznikov et al. experiment [1]. A straightforward kinetic approach explains both constant-voltage and constant-current results, while automatically securing conservation. We discuss why the nonequilibrium noise of a quantum point contact cannot be some kind of shot noise, as commonly believed: it is a hot-electron uctuation e ect unique to quasione-dimensional mesoscopic conductors. Shot noise { if present at all { is unimportant here.

Our treatment starts with orthodox quantum trans-

port in m etals [7, 8, 9]. A uniform one-dimensional ballistic wire is intimately contacted to large source and drain reservoirs. The reservoir leads, permanently neutral and equilibrated, pin the local chemical potential at each interface with the wire. At the interfaces, the perturbed carrier distribution goes smoothly to its equilibrium form in the leads, set by the local chemical potential.

A generator forces an electron current into the wire at the source and rem oves it through the drain. In open-system conduction, the active injection and extraction of external current is necessary and su cient to ensure charge conservation not only microscopically, but globally [10]. This is a nontrivial and mandatory constraint on any microscopic account of noise and transport.

The external current evokes a resistivity-dipole eld E within the uniform wire as the carrier density at both interfaces adjusts to the disturbance. The standard kinetic equation for the electron distribution  $f_k$  (t) is

$$\frac{\partial f_{k}(t)}{\partial t} + \frac{eE}{\sim} \frac{\partial f_{k}(t)}{\partial k} = \frac{1}{in(\mathbf{w}_{k})} f_{k}(t) \frac{h_{in}^{-1} f(t)i}{h_{in}^{-1} f^{eq}(;k_{B}T)i} f_{k}^{eq}(;k_{B}T) \frac{1}{el(\mathbf{w}_{k})} \frac{f_{k}(t) f_{k}(t)}{2} : \tag{1}$$

The inelastic and elastic relaxation rates, 1=  $_{\rm in}$  and 1=  $_{\rm el}$  respectively, param etrize the collision term . They may depend on subband electron energy " $_{\rm k}$ . Expectations h::i trace over wavevector space and spin; for example, h  $_{\rm in}^{-1}$  f (t)i = 2  $_{\rm in}$  (" $_{\rm k}$ )  $^{1}$  f  $_{\rm k}$  (t)dk=2 . The equilibrium function f  $^{\rm eq}$  ( ; $_{\rm k}$  B T ) has the usual Ferm i-D irac form , dependent on them ical potential and therm alenergy k B T .

C rucially, the collisional structures on the right of Eq. (1) secure charge and number conservation. These es-

sential properties are inherited by the dynam ical mean-square number uctuation  $f_k$  (t) in the structure, determining all the correlation functions of physical interest [8, 11]. The equation for  $f_k$  (t) is systematically generated by varying both sides of Eq. (1). Microscopic conservation is built in . So are the sum rules [2, 3].

In the low-frequency lim it the noise spectral density in a QPC is duly obtained. For a device of operational length L, subject to current I, it has the functional form

$$S^{xs}(I; ) = \begin{cases} Z_{1} & Z_{L=2} & Z_{L=2} \\ dt & dx & dx^{0} C_{JJ}(x & x^{0}; I; ;t) & C_{JJ}(x & x^{0}; I = 0^{+}; ;t) ; \end{cases}$$
(2)

we rem ove the equilibrium Johnson-Nyquist noise oor (I! 0). The nonequilibrium current-current correlator  $C_{\rm JJ}$  (x  $x^0;I;$ ;t) is computed from the Green function for the spatially dependent version of Eq. (1). For further details of our QPC model see Ref. 11.

Equation (1) and its variations are not restricted to weak applied currents.  $C_{\rm JJ}$  is derived within a fully nonequilibrium description, not only conserving but equally valid at strong elds [8] as at weak. The ability to do this, in a strictly conserving way, is an absolute pre-

requisite for analyzing the experiment of Ref. 1, whose conditions take a QPC far out of the weak-eld, highly degenerate limit addressed by Khlus [5] and others [6].

For collision times  $_{\rm el}$  and  $_{\rm in}$  independent of subband energy " $_{\rm k}$ , the nonequilibrium problem is exactly solvable [11]. We now focus on a physical model for the behavior of these times in a strongly nonequilibrium environment.

Let us start with elastic scattering. Since the quantum point contact is impurity-free, its elastic mean free path (MFP) is matched to L, the operational length of

the ballistic core. The elastic scattering rate will not be sensitive to the driving eld. The characteristic velocity of the carriers is  $v_{av}$  hyj $f^{eq}$  i=n at the QPC electron density  $n=hf^{eq}$ i. Thus the elastic time is

$$el = L = V_{av}$$
: (3)

In the pincho  $\lim$  it, far below the subband threshold " $_1$ , the density  $n = e^{("_1)^{-k_B}T}$  vanishes. The carriers are classical;  $v_{av}$  is them al. For " $_1$   $k_B$  T (degenerate  $\lim$  it)  $v_{av}$ !  $v_F$ ; it is the Fermi velocity in the subband.

The behavior of  $_{\rm el}$  re ects the constancy of the elastic M FP. The inelastic M FP, however, will decrease substantially with increasing source-drain voltage. The eld-excited electrons will shed excess energy by emitting many more phonons. We model this inelastic loss via

$$_{in} (V; ) = _{el} \frac{"_{av}}{eV} \tanh \frac{eV}{"_{av}} :$$
 (4)

The driving voltage is V = EL while " $_{av} = \frac{1}{2} m \ v_{av}^2$  is the characteristic energy of the subband population; it is therm almearpincho and Ferm iathigh lling. The ratio eV=" $_{av}$  determ ines the inelasticity. At high degeneracy, " $_{av} =$ " $_{1}$   $k_B$  T and Pauli exclusion inhibits phonon em ission. The parameters and are set once (to = 0:52 and = 0:6) to m atch the peaks at 250 and 300nA in Fig. 1. These values then determ ine all our results.

In the low-eld limit, in (V; )! el. This is the condition for ideal ballistic transport in an open contact, when all dissipation is in the leads. It yields Landauer's quantized conductance steps across the subband thresholds [9]. As eld-induced phonon emission sets in, the inelastic MFP rapidly shrinks below L. Eq. (4) encodes this nonideal behavior.

In our param etrized inelastic model, Eq. (2) for the excess noise in the rstQPC subband becomes [11]

The conductance G(I; ) = I=V is

G(I;) 
$$\frac{2e^2}{h}T_1(I;) = \frac{2e^2}{h} \frac{v_F}{v_{av}} \frac{2_{in}}{e_1 + i_0}$$
: (6)

At xed current this determ ines the corresponding voltage. The relation is nonlinear owing to the implicit V-dependence through in from Eq. (4). Second, as required by its sum rule [3], the compressibility =  $n^{-1}$ @ ln n=@ appears (in ratio with its classical value  $_{cl}$  = 1=nk<sub>B</sub> T).

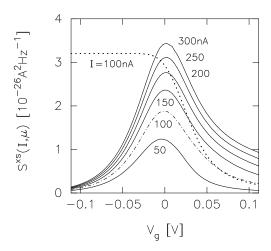


FIG. 2: Excess hot-electron noise at  $1.5 \mathrm{K}$  in a QPC at its rst subband threshold, computed with our strictly conserving Eq. (5), as a function of gate voltage (relative to the rst threshold), at xed levels of source-drain current. There is close quantitative a nity of our peaks to the experimentally observed rst-threshold maxima in Fig. 1 [1]. Dotted line: corresponding prediction at  $I = 100 \mathrm{nA}$  from a widely adopted theory of QPC noise [6], using our transmissivity  $I_1$  (Eq. (6)) as that model's phenomenologically required input. Compare it with the kinetic result at  $100 \mathrm{nA}$  (chain line).

The last factor on the right of Eq. (5) is highly sensitive to the ratio  $_{\rm in}=_{\rm el}$  out of equilibrium [11].

In Fig. 2 we display the result of our conserving computation, in plan enting the physics of Eqs. (3) { (6). Most dram atic are the peak structures at the threshold =  $\mathbf{"}_1$  as the chem ical potential takes n in the channel from low to high values. The quantitative t to the as-measured peaks of Fig. 1 is noteworthy. The conventionally predicted shot-noise analog [6] is entirely wide of the mark.

W hat are the peaks? The peaks are a snapshot of the carriers' transition from classical to quantum behavior. They are generated by strongly competing trends within  $S^{xs}(I;)$ : the compressibility, and the combination of collision times in the numerator with G(I;) in the denominator. Consider the  $\lim_{x\to a} f(I;)$ 

(i) Degenerate lim it. Then =  $_{\rm cl}$ !  $k_{\rm B}$  T=2 ( "1) 1 even as the collision-time factor reaches its ideal maximum of 1:75  $_{\rm el}^2$  and G plateaus out at  $2{\rm e}^2$ =h. We have

$$S^{xs}(I;) / (= c_1) (e_1 = L)^2 n^4 :$$
 (7)

(ii) P incho lim it. At low densities, the carriers are classical. The compressibility ratio =  $_{\rm cl}$  goes to a maximum of unity. At low n, though, carriers are highly energized. Eq. (4) tells us that

$$V = I = G / I = (n_{in} (V; )) ! I = (nV ):$$
 (8)

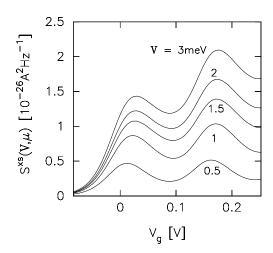


FIG. 3: Excess hot-electron noise in a QPC at  $1.5 \mathrm{K}$  for its rst two subbands, at constant applied voltage V, as a function of gate voltage (referred to 1st threshold). This corresponds to Fig. 2 of Ref. 1. The quasi-linear dispersion of the peaks with V shows that such dispersion is not unique to shot noise.

That is, eV (I; )  $n^{1=(1)}$  "av. The direct dependence of S xs on the collision times, along with G /  $n_{in}$  in the denominator, then yields the overall asymptote

$$S^{xs}(I; ) / (= _{cl})_{in}(V; )=n$$
 
$$(n^{1=(1)}) = n = n^{(2-1)=(1)} : (9)$$

In either case Eqs. (7) and (9) lead to vanishing shoulders. In the neighborhood of the threshold, the peaks in  $S^{xs}(I; )$  are the outcome of the compressibility, heralding the onset of degeneracy, playing against the dynamics of nonequilibrium dissipative scattering in the channel.

We present in Fig. 3 the results of our noise model at constant voltage. Comparing it with the corresponding Fig. 2 of Reznikov et al. [1], we again see a concordance between observations and the kinetic calculation.

It is in portant to exam ine two aspects of the Reznikov et al. noise data, in light of what is needed to explain it.

(a) Linear response is inapplicable. A quick estim ate shows that the experim ent lies well beyond the lim its of weak—eld linear models which perturb a system mildly away from its Fermi surface [6]. In the experimental regime of Fig. 3 the gate voltage sweeps the channel's Fermi energy from larger, safe values (calibrating G against measurements, we see that 3 meV covers three subbands), far down to where carriers are not degenerate at all, but classical.

In Fig. 3 the applied voltage goes up to 3m eV. Since eV & , linear response is clearly unjustied. M uch m ore extreme is Fig 2, for constant current. Eq. (8) shows just how rapidly V reaches enormous values at channel densities below threshold.

The severe limitation of weak-eld models has not inhibited their wide use in data analysis [1, 4, 6]. We stress that a properly constructed, fully nonequilibrium kinetic approach { one that is strictly conserving { is the only appropriate analytical tool.

(b) There is no shot noise. Eq. (2) and its specic c form Eq. (5) do not describe shot noise. They describe hot-electron noise, whose therm odynam ic origin is dierent [8]. This is bome out starkly by the peak structures of Fig. 1, in patent contradistinction to shot-noise based predictions [6]. Moreover, near-linearity of the peaks in Fig. 3 with V is not special to shot noise [1]. Such dispersion arises naturally from inelastic dynam ics.

Finally, readers will note that the noise plateaux at very low densities in Fig. 1 are not reproduced by those m odels that enforce full shot noise (whose plateaux are far too big), nor by the collisionalm odel, in its presently simplied form. What is really needed is a fuller theory that can cross from the one-dimensionally conned QPC state to one where the low-density, high-energy electrons are so excited as to break the connement and fan out, nonuniform ly and at high momenta, into the drain.

We have presented a microscopically grounded theory of nonequilibrium mesoscopic noise. It is based on standard and rigidly conservative kinetics. Thus it is well controlled, and the whole range of relevant noise properties of a quantum point contact [1, 4] is well reproduced. For the rist time, we explain qualitative and quantitative experimental features that other theories [6] missentirely.

We have accounted for the prominent and enigmatic noise peaks that have deed explanation until now. The central role of the electronic compressibility has been identified and quantified as an essential physical determinant of mesoscopic uctuations. That is true not only in QPCs but in all conductive structures at these scales.

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